# Important Note: 1. On completing your answers, compulsorily draw diagonal cross lines on the populating blank page.

νε εφαριστε written eg, 42±8 → 30, will be treated as malpractice.

# GECS SCHEME

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## Third Semester B.E. Degree Examination, June/July 2018 Physical and Chemical Principles of Nano Technology

Time: 3 hrs. Max. Marks: 80

Note: Answer any FIVE full questions, choosing ONE full question from each module.

### Module-1

1	a.	Define quantum mechanics. State uncertainty principle with an example and accomplementoriy.	id a note on
	b.	State and explain dual nature of matter by debrogllie.	(05 Marks)
	c.	Derive an expression for uncertainty principle with but on the	(03 Marks)

Derive an expression for uncertainty principle with help of localization experiment.

Enumerate Planck's hypotheses.

(04 Marks) (04 Marks)

### OR

Give a brief note on valance Bond theory and its applications.

े(05 Marks)

Write a brief note on molecular orbital theory and its application.

(06 Marks)

Write a short note on computational chemistry and name few applications.

(05 Marks)

### Module-2

Define thermodynamics. Write a note on importance and limitations of thermodynamics. 3

State and explain the first law of thermodynamics with mathematical expressions. (08 Marks)

### OR

Define entropy. Give a brief note on the illustration of the concept of entropy.

(06 Marks)

Explain the concept of heat capacity at constant volume and constant pressure.

(06 Marks)

What is spontaneous process? Write the criteria for spontaneity.

(04 Marks)

### Module-3

Explain Debye theory of molar heat capacity and limitations. 5

(08 Marks)

Derive Kronig-Penny model.

(08 Marks)

### OR

Explain classical theory of molar heat capacity and limitations.

(06 Marks)

Distinguish between metal, insulator and semiconductor.

(06 Marks)

Discuss the concept of Lattice vibrations and thermal heat capacity.

(04 Marks)

### Module-4

7 a. Explain the following:

i) Intrinsic semiconductors

ii) Extrinsic semiconductors.

b. Discuss the concept of tunnelling.

c. Explain brief about classical and quantum tunnelling.

OR

8 a. Explain briefly P-N junction semiconductor diode and give its advantages.

b. Write a note on rectification.

(08 Marks)

(04 Marks)

(04 Marks)

(04 Marks)

(06 Marks)

### Module-5

9 a. Discuss the following optical properties of colloids:

(06 Marks)

Write about the following electric properties of colloids:

i) Electrophoresis

(96 Marks)

ii) Electro osmosis.Write a note on classification of emulsions with example.

(04 Mark

### OR

10 a. Explain the classification of colloids based on the nature of dispersed phase with example (06 Mark)

b. Explain about crystalloids and colloids.

(04 Marks)

c. Explain the following dynamic properties of colloids:

i) Brownian movement

ii) Sedimentation

iii) Diffusion.

(06 Mark \*\*